

APSEMI PhotoRelays

APSEMI Photorelays are the most reliable, technically advanced logic-to-power interface devices. Their basic function is to take a low current signal from a microprocessor to control the switching of both AC and DC loads, while providing an isolation barrier between logic and power. While this function is common to all relays, Photorelays provide distinct advantages over their mechanical counterparts including:

- Long life (No limit on mechanical and electrical
- lifetime)Bounce-free switching
- Higher speed and high frequency switching
- Higher sensitivity (less power consumption)
- Immunity to EMI or RFI

- No have voltaic arc, bounce, and noise More
- resistant to vibration and impact AC or DC load
- switching
- Small package size

- Applications

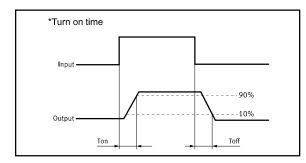
These advantages make APSEI Photorelays the ideal choice for:

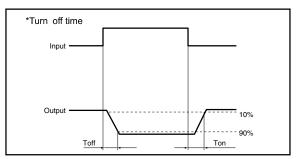
- Telecom/Datacom switching .
- Multiplexers
- Meter reading systems •
- Data acquisition •
- Medical equipment
- Battery monitoring
- I/O Sub-Systems .

- Robotics • Aerospace
- Home/Safety security systems
- Process Control
- **Energy Management**
- Reed Relay EMR Replacement
- Programmable Controllers

TPYES

Category	Output Rating		Dealizate	Devit Nie	Dealize Overtity	
	Load Voltage	Load Current	Package	Part No.	Packing Quantity	
AC/DC	60V 400mA		DIP-8	APW612E	50pcs /tube	
		SMD-8	APW612EH	1000pcs /reel		





SPST-NO+NC (1 Form A/B) APW612_E/EH SMD-8 / DIP-8 Load Voltage:60V Load Current:400mA

Absolute Maximum Ratings (Ta = 25°C)

ltem		Symbol	Value	Units	Note
	Continuous LED Current	IF	50	mA	
Input	Peak LED Current	IFP	1000	mA	f=100Hz, duty=1%
	LED Reverse Voltage	VR	5	V	
	Input Power Dissipation	Pln	75	mW	
	Load Voltage	VL	60	V(AC peak or DC)	
Output	Load Current	IL	400	mA	
	Peak Load Current	IPeak	700	mA	1ms(1 pulse)
	Output Power Dissipation	Pout	450	mW	
Total Power Dissipation		PT	500	mW	
I/O Breakdown Voltage		VI/O	5000	Vrms	RH=60%, 1min
Operating Temperature		TOpr	-40 to +85	-40 to +85	
Storage Temperature		TStg	-40 to +100	-40 to +100	
Pin Soldering Temperature		TSol	260	260	10 sec max.

Electrical Characteristics (Ta = 25°C)

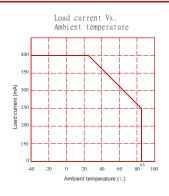
	Item	Symbol	MIN.	TYP.	MAX.	Units	Conditions	
	LED Forward Voltage	VF		1.2	1.4	V	IF=10mA	
Input	Operation LED Current	IF On		0.5	5.0	mA		
	Recovery LED Current	IF Off		0.35	0.5	mA		
	Recovery LED Voltage	VF Off	0.5			V		
Output	On-Resistance	ROn		1(N.O.)	1.4(N.O.)	Ω	IF=5mA (N.O.) IF=0mA (N.C) IL=100mA Time to flow is within 1 sec.	
				6(N.C.)	10(N.C.)			
	Off-State Leakage Current	ILeak		1	10	uA	IF=0mA (N.O.) IF=5mA (N.C) VL= Rating	
	Output Capacitance	COut		150		pF	IF=5mA,VL=0, f=1MHz	
Transmis sion	Turn-On Time	TOn		0.23(N.O.)	0.5(N.O.)	ms	IF=5mA, IL=50mA	
				0.2(N.C.)	1.0(N.C.)			
	Turn-Off Time	TOff		0.03(N.O.)	0.2(N.O.)	ms	1	
				0.5(N.C.)	3.0(N.C.)			
Coupled	I/O Isolation Resistance	RI/O	10 ¹⁰			Ω	DC500V	
	I/O Capacitance	CI/O		0.8		pF	f=1MHz	

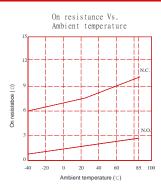
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value): IF ≥5mA and ≤30mA

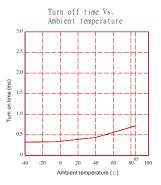
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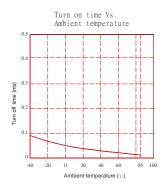
SPST-NO+NC (1 Form A/B) APW612_E/EH SMD-8 / DIP-8 Load Voltage:60V Load Current:400mA

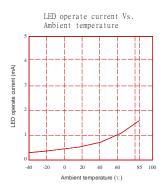
Engineering Data

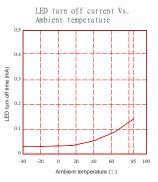




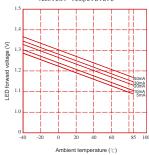


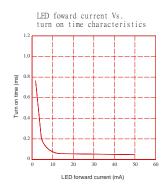






LED forward voltage Vs. Ambient temperature

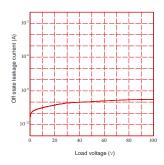




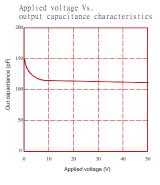
Voltage Vs. currennt characteristics of output at MOS portion

	4 5 e, V

Off state leakage current



LED foward current Vs. turn off time characteristics

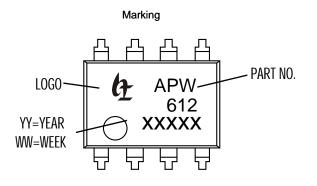


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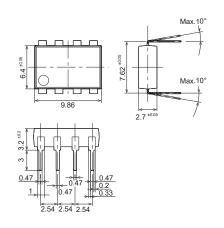


SPST-NO+NC (1 Form A/B) APW612_E/EH SMD-8 / DIP-8 Load Voltage:60V Load Current:400mA

Dimensions and DIP-8 Package Unit: mm

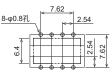


Through hole terminal type



Lable





DIP Tape dimensions Unit : mm

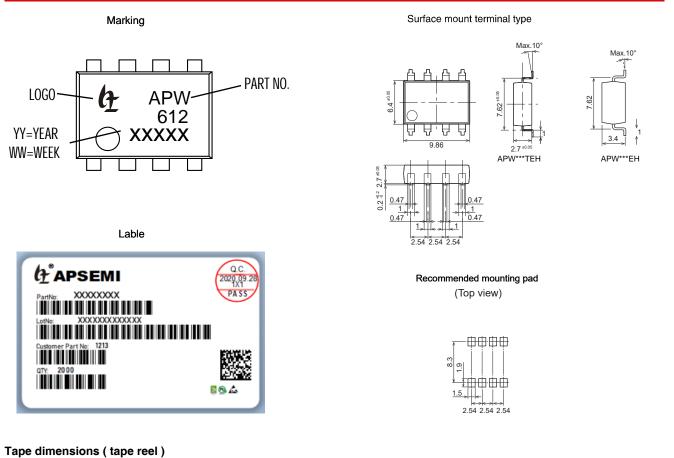
Devices are packaged in a tube so that pin No. 1 is on the stopper B side. Observe correct orientation when mounting them on PC boards.

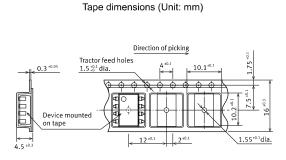




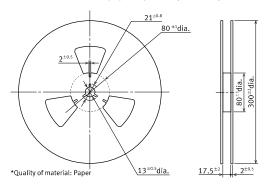
SPST-NO+NC (1 Form A/B) APW612_E/EH SMD-8 / DIP-8 Load Voltage:60V Load Current:400mA

Dimensions and SMD-8 Package Unit: mm





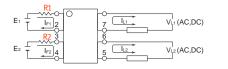
Dimensions of paper tape reel (Unit: mm)





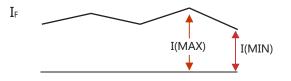
Using Methods

Examples of resistance value to control LED forward current (IF=5mA)



E1 E2	R1 R2(Approx)
3.3V	300 Ω
5.0V	600 Ω
12V	1.9KΩ
24V	4.1K Ω

LED forward current must be more than 5mA , at I(MIN) ,and less than 30mA , at I(MAX).



Recommended Operating Conditions

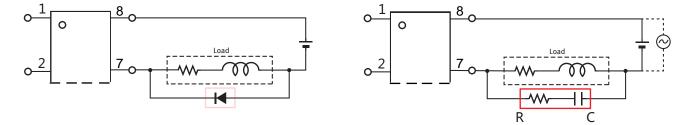
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value):

Characteristic	Symbol	Min	Тур.	Max	Unit
Forward current	١ _F	5.0	7.0	30	mA

Protection Circuit

Clamp diode is connected in parallel with the load. Absorb capacity with external diode.

CR Snubber is connected in parallel with the load. Absorb capacity with buffer capacity.



When adding diodes, buffer circuits (C-R), and other protections, they need to be installed near the MOS RELAY to be effective. Adding protection elements may result in a slow reset time, so adjust them according to the actual situation before use.

Note: When developing designs using this product, perform the expected performance of the equipment under the operating conditions recommended by the guidelines in this document. Continuous use under heavy loads (including, but not limited to, the application of high temperatures/current/voltage and significant changes in temperature, etc.) may result in deterioration of the reliability of this product.

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